Favorable consideration and allowance are earnestly solicited.

Respectfully submitted, BROWDY AND NEIMARK, P.L.L.C. Attorneys for Applicant

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Sheridan Neimark Registration No. 20,520

SN:sfg

Telephone No.: (202) 628-5197
Facsimile No.: (202) 737-3528
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VERSION WITH MARKINGS TO SHOW CHANGES MADE

Claims 4 and 6 have been amended as follows:

- 4 (Amended).—An interposer for use in a semiconductor device in which a clad plate as defined in any one of claims 1 [to 3] or 2 is etched selectively to form connecting bumps with a semiconductor chip and a wiring layer, the semiconductor chip and the wiring layer are connected by way of the semiconductor chip connection bumps using anisotropically conductive adhesives and conduction of the interposer in the direction of the thickness is taken by way of a columnar conductor formed by etching.—
- 6. (Amended). -- A method of manufacturing an interposer-forming clad layer for use in a semiconductor device as defined in any one of claims 1 [to 3] or 2 wherein the interposer-forming clad plate for use in the semiconductor device is formed by previously applying an activating treatment to the bonded surfaces of the copper foil and the nickel foil or nickel plating in a vacuum vessel and them laminating the copper foil and the nickel foil material or nickel plating and cold pressbonding them at a rolling reduction of 0.1 to 3% in which the activating treatment is applied <1> in an inert gas atmosphere at an extremely low pressure of 1 x 10^1 to 1 $\times 10^{-2}$ Pa, <2> using the nickel plated copper foil material and the copper foil material as one electrode A having the bonding surfaces grounded to the earth, respectively, and conducting glow discharge by applying an AC current at 1 to 50 MHz between it and the other electrode B supported insulatively and <4>applying sputter etching, <3> with the area of the electrode exposed in plasmas caused by the glow discharge being 1/3 or less of the electrode B.--